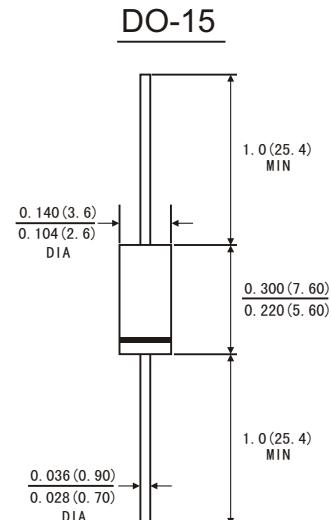


## FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds at terminals

## MECHANICAL DATA

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014 ounce, 0.39 gram



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%).

	Symbols	SR 320	SR 330	SR 340	SR 350	SR 360	SR 380	SR 3100	SR 3150	SR 3200	Units				
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	Volts				
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	57	71	105	140	Volts				
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	Volts				
Maximum average forward rectified current 0.375" (9.5mm) lead length (See Fig.1)	I <sub>(AV)</sub>	3.0								Amps					
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	80.0								Amps					
Maximum instantaneous forward voltage at 3.0 A (Note 1)	V <sub>F</sub>	0.55		0.70		0.85		0.90		0.95					
Maximum instantaneous reverse current at rated DC blocking voltage (Note 1)	I <sub>R</sub>	0.2								mA					
T <sub>J</sub> =25°C		20		10											
Typical junction capacitance (Note 3)	C <sub>J</sub>	250		160							pF				
Typical thermal resistance (Note 2)	R <sub>θJA</sub> R <sub>θJL</sub>	40.0 10.0								°C/W					
Operating junction temperature range	T <sub>J</sub>	-65 to +150								°C					
Storage temperature range	T <sub>STG</sub>	-65 to +150								°C					

Notes: 1. Pulse test: 300 μs pulse width, 1% duty cycle

2. Thermal resistance from junction to lead vertical P.C.B. mounted, 0.5" (12.7mm) lead length

with 2.5X2.5" (63.5X63.5mm) copper pads

3. Measured at 1MHz and reverse voltage of 4.0volts

FIG.1-FORWARD CURRENT DERATING CURVE

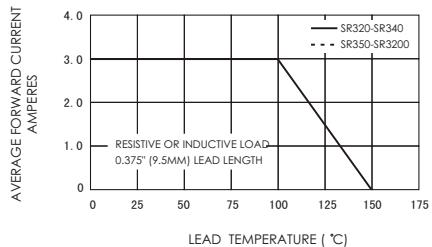


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

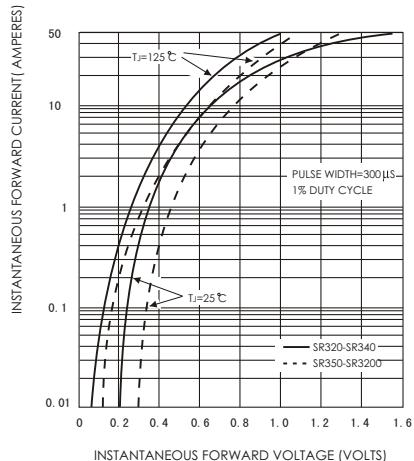


FIG.5-TYPICAL JUNCTION CAPACITANCE

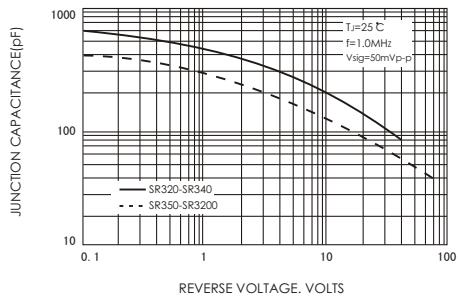


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

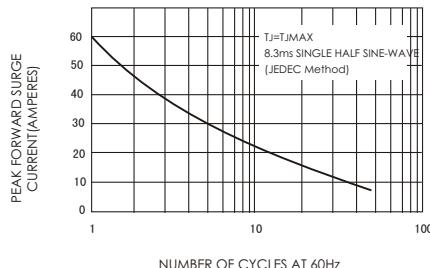


FIG.4-TYPICAL REVERSE CHARACTERISTICS

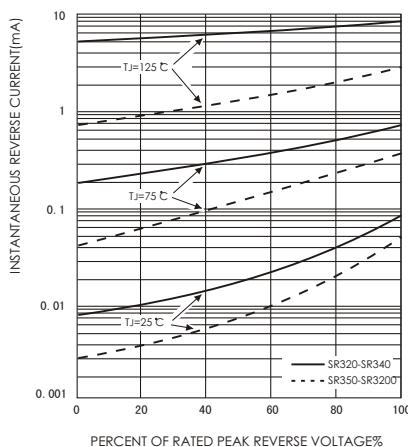


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

